

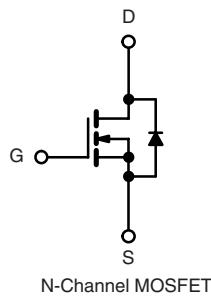
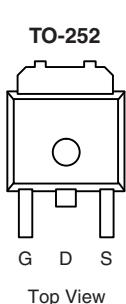
## N-Channel 30-V (D-S) MOSFET

### PRODUCT SUMMARY

$V_{DS}$ (V)	$R_{DS(on)}$ ( $\Omega$ )	$I_D$ (A) <sup>a, g</sup>	$Q_g$ (Typ.)
30	0.0041 at $V_{GS} = 10$ V	60 <sup>g</sup>	34 nC
	0.0059 at $V_{GS} = 4.5$ V	60 <sup>g</sup>	

### FEATURES

- Halogen-free
- TrenchFET® Gen III Power MOSFET
- 100 %  $R_g$  Tested
- 100 % Avalanche Tested



### APPLICATIONS

- Low-Side Switch for DC/DC Converters
  - Servers
  - POL
  - VRM
- OR-ing

### ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	
Continuous Drain Current ( $T_J = 150$ °C)	$I_D$	60 <sup>g</sup>	A
		60 <sup>g</sup>	
		36 <sup>b, c</sup>	
		29 <sup>b, c</sup>	
Pulsed Drain Current	$I_{DM}$	80	
Continuous Source-Drain Diode Current	$I_S$	60 <sup>g</sup>	W
		4.9 <sup>b, c</sup>	
Single Pulse Avalanche Current	$I_{AS}$	50	
Single Pulse Avalanche Energy	$E_{AS}$	125	
Maximum Power Dissipation	$P_D$	83	
		53	
		5.4 <sup>b, c</sup>	
		3.4 <sup>b, c</sup>	
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	- 55 to 150	°C
Soldering Recommendations (Peak Temperature)		260	

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient	$R_{thJA}$	18	23	°C/W
Maximum Junction-to-Case (Drain)	$R_{thJC}$	1.0	1.5	

Notes:

- Based on  $T_C = 25$  °C.
- Surface Mounted on 1" x 1" FR4 board.
- $t = 10$  s.

**SPECIFICATIONS**  $T_J = 25^\circ\text{C}$ , unless otherwise noted

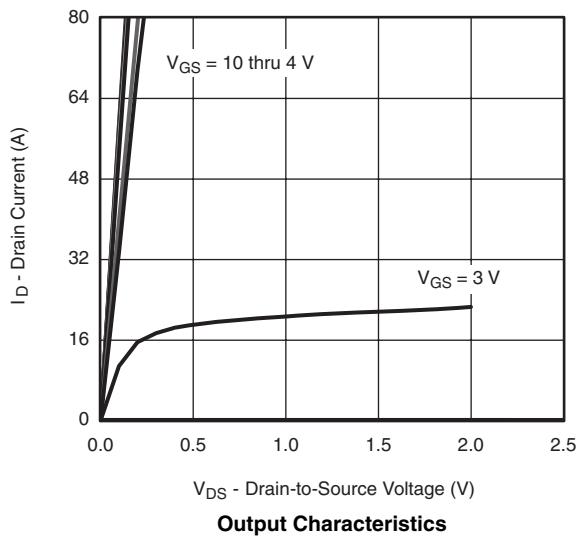
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit	
<b>Static</b>							
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	30			V	
$V_{DS}$ Temperature Coefficient	$\Delta V_{DS}/T_J$	$I_D = 250 \mu\text{A}$		28		mV/ $^\circ\text{C}$	
$V_{GS(\text{th})}$ Temperature Coefficient	$\Delta V_{GS(\text{th})}/T_J$			- 6.6			
Gate-Source Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$	1.2		2.5	V	
Gate-Source Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			$\pm 100$	nA	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$		1		$\mu\text{A}$	
		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^\circ\text{C}$			10		
On-State Drain Current <sup>a</sup>	$I_{D(\text{on})}$	$V_{DS} \geq 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			A	
Drain-Source On-State Resistance <sup>a</sup>	$R_{DS(\text{on})}$	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		0.0031	0.0041	$\Omega$	
		$V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$		0.0043	0.0059		
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = 10 \text{ V}, I_D = 20 \text{ A}$		100		S	
<b>Dynamic<sup>b</sup></b>							
Input Capacitance	$C_{iss}$	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		4590		pF	
Output Capacitance	$C_{oss}$			810			
Reverse Transfer Capacitance	$C_{rss}$			320			
Total Gate Charge	$Q_g$	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		74	110	nC	
Gate-Source Charge	$Q_{gs}$			34	51		
Gate-Drain Charge	$Q_{gd}$			12			
Gate Resistance	$R_g$		$f = 1 \text{ MHz}$	10			
Turn-On Delay Time	$t_{d(\text{on})}$	$V_{DD} = 15 \text{ V}, R_L = 1.5 \Omega$ $I_D \geq 10 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		0.2	0.8	1.6	$\Omega$
Rise Time	$t_r$			19	35	ns	
Turn-Off Delay Time	$t_{d(\text{off})}$			5	10		
Fall Time	$t_f$			45	85		
Turn-On Delay Time	$t_{d(\text{on})}$			5	10		
Rise Time	$t_r$	$V_{DD} = 10 \text{ V}, R_L = 1 \Omega$ $I_D \geq 10 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 1 \Omega$		45	85	ns	
Turn-Off Delay Time	$t_{d(\text{off})}$			18	45		
Fall Time	$t_f$			60	110		
				30	60		
<b>Drain-Source Body Diode Characteristics</b>							
Continuous Source-Drain Diode Current	$I_S$	$T_C = 25^\circ\text{C}$			60	A	
Pulse Diode Forward Current <sup>a</sup>	$I_{SM}$				80		
Body Diode Voltage	$V_{SD}$	$I_S = 4 \text{ A}$		0.72	1.1	V	
Body Diode Reverse Recovery Time	$t_{rr}$	$I_F = 10 \text{ A}, dI/dt = 100 \text{ A}/\mu\text{s}, T_J = 25^\circ\text{C}$		33	50	ns	
Body Diode Reverse Recovery Charge	$Q_{rr}$			25	40	nC	
Reverse Recovery Fall Time	$t_a$			16		ns	
Reverse Recovery Rise Time	$t_b$			17			

Notes:

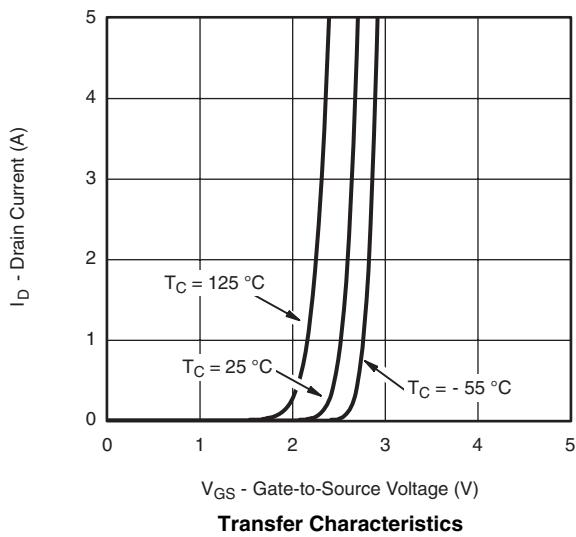
- a. Pulse test; pulse width  $\leq 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

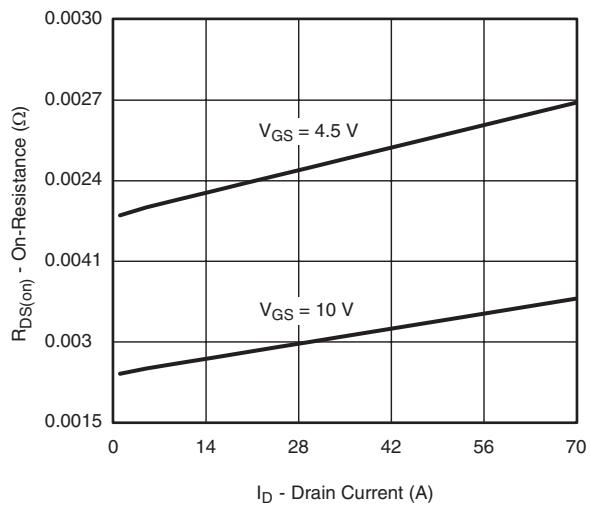
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



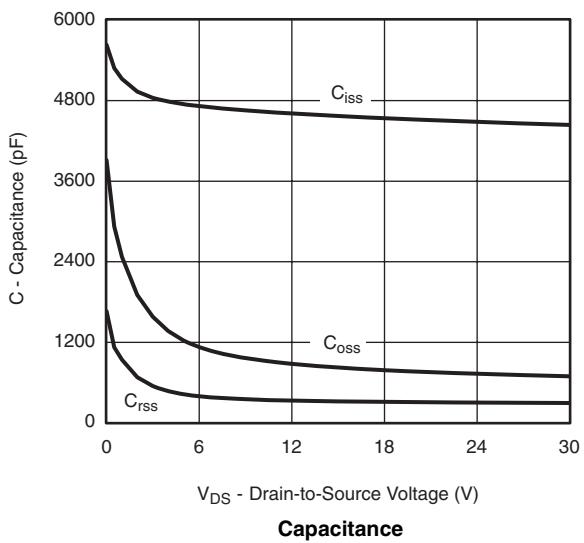
**Output Characteristics**



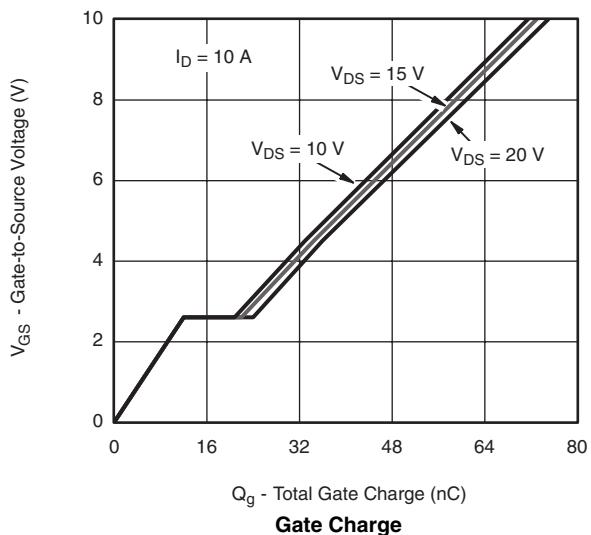
**Transfer Characteristics**



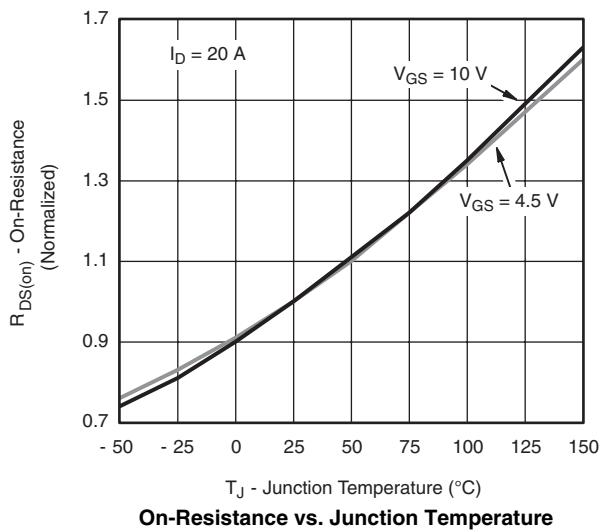
**On-Resistance vs. Drain Current and Gate Voltage**



**Capacitance**

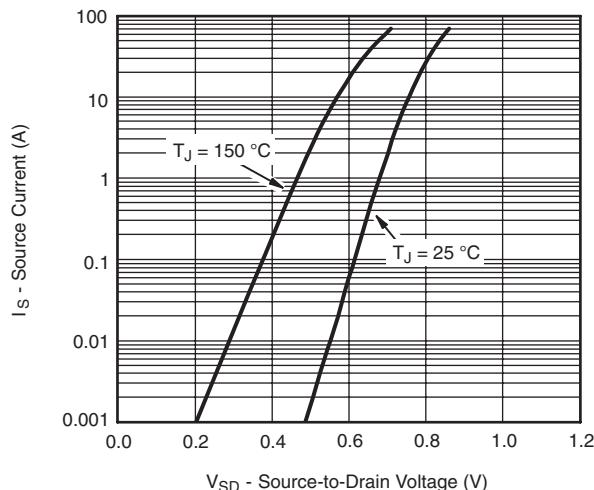


**Gate Charge**

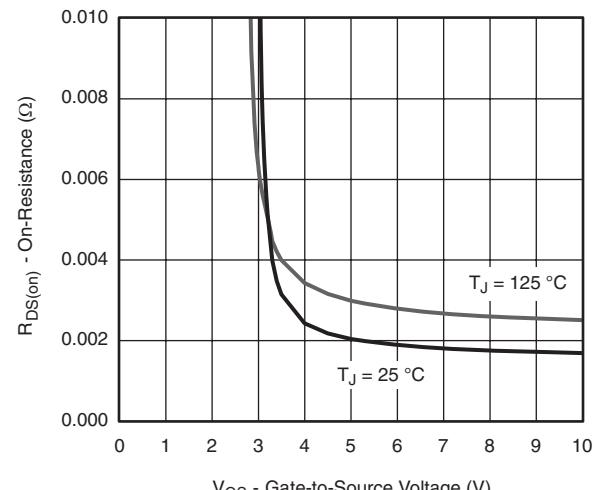


**On-Resistance vs. Junction Temperature**

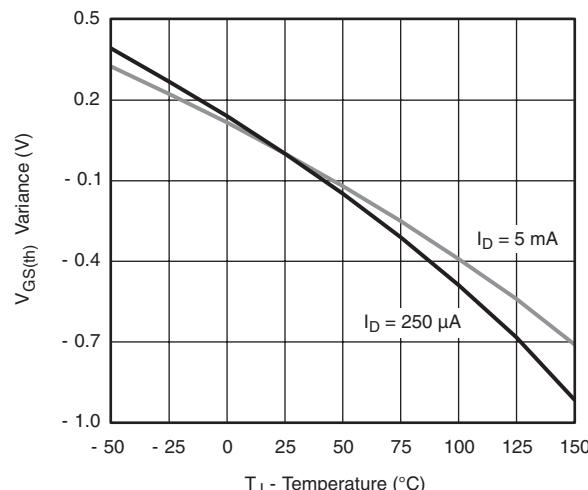
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



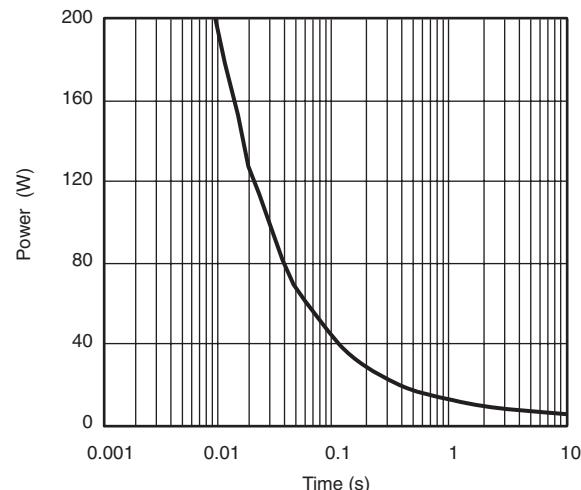
Source-Drain Diode Forward Voltage



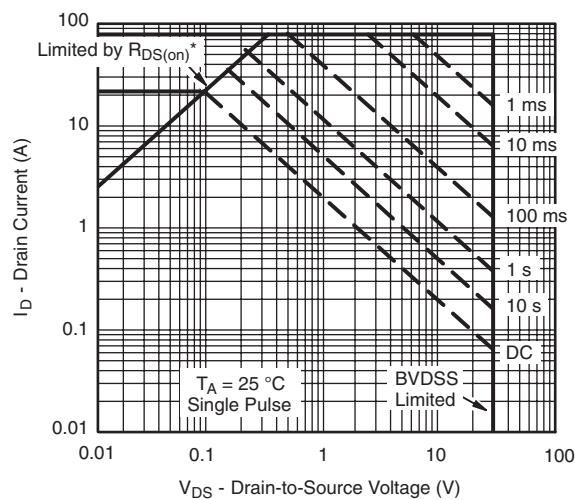
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage

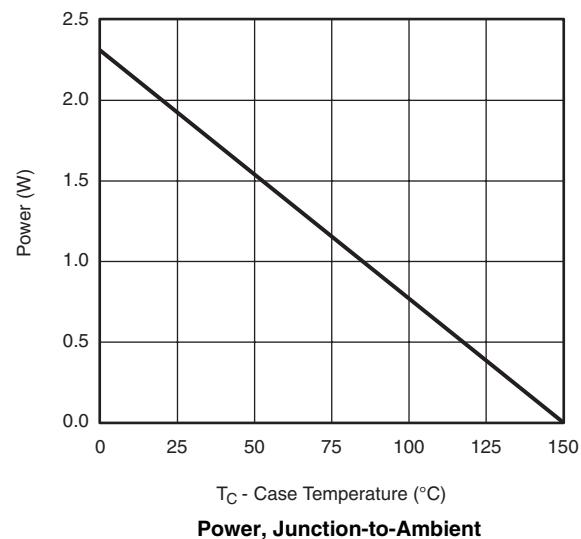
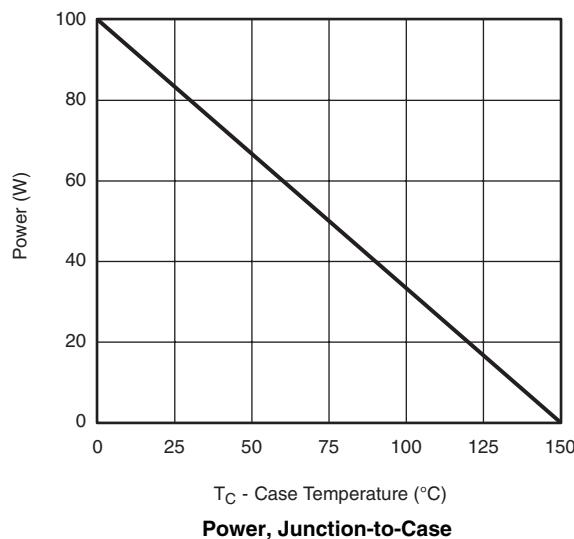
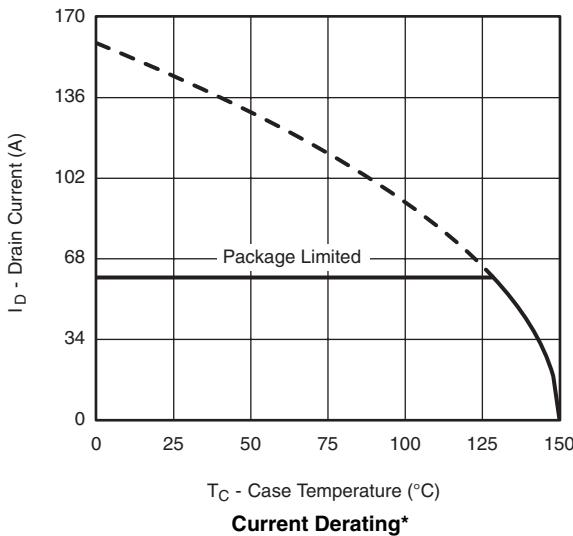


Single Pulse Power, Junction-to-Ambient



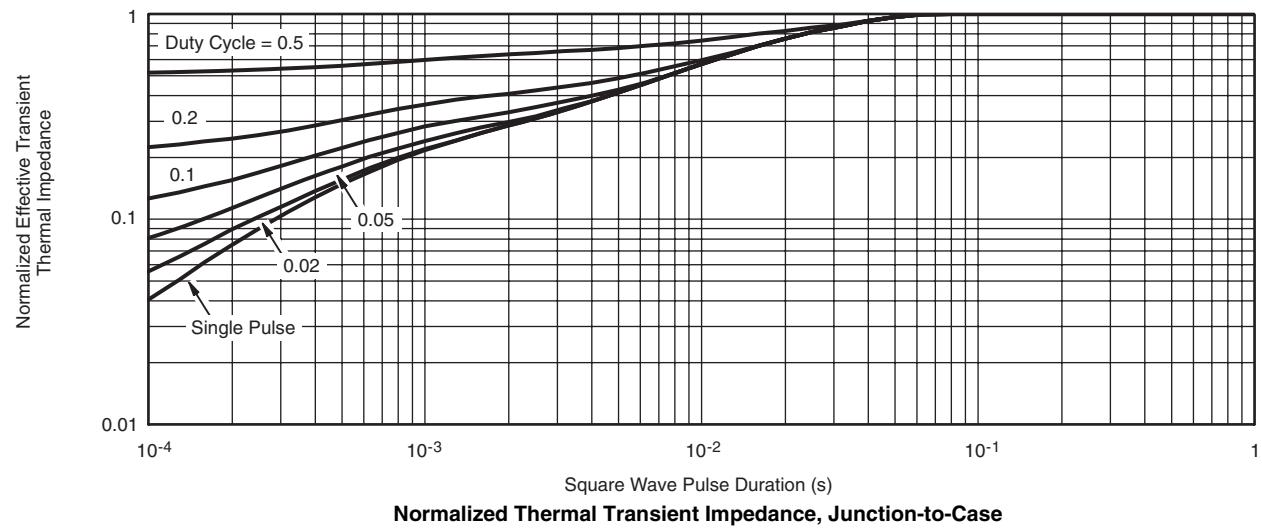
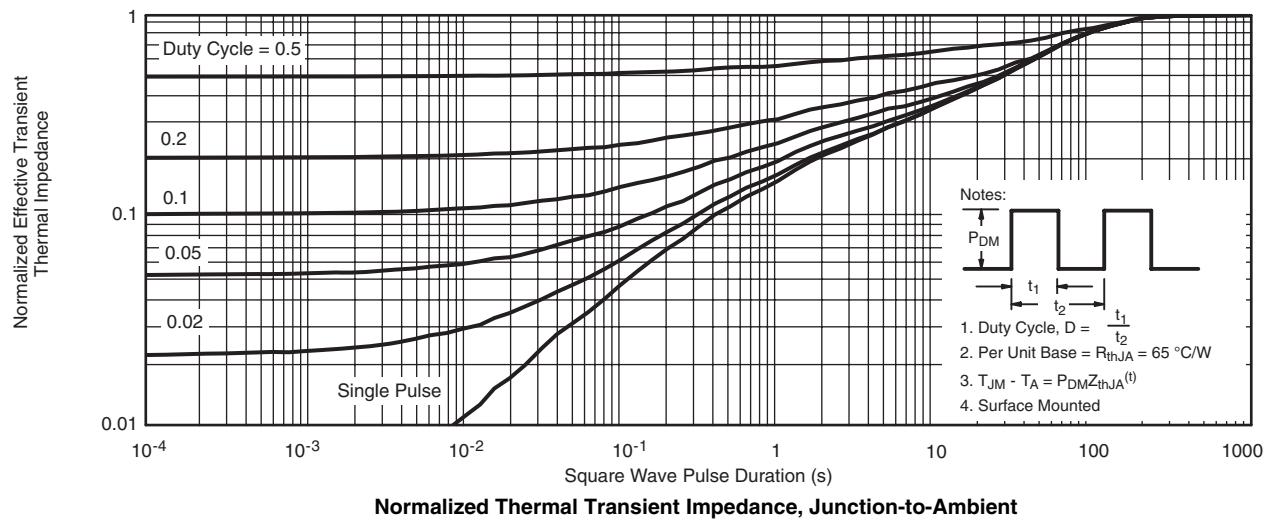
\*  $V_{GS} > \text{minimum } V_{GS}$  at which  $R_{DS(on)}$  is specified  
Safe Operating Area, Junction-to-Ambient

**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted

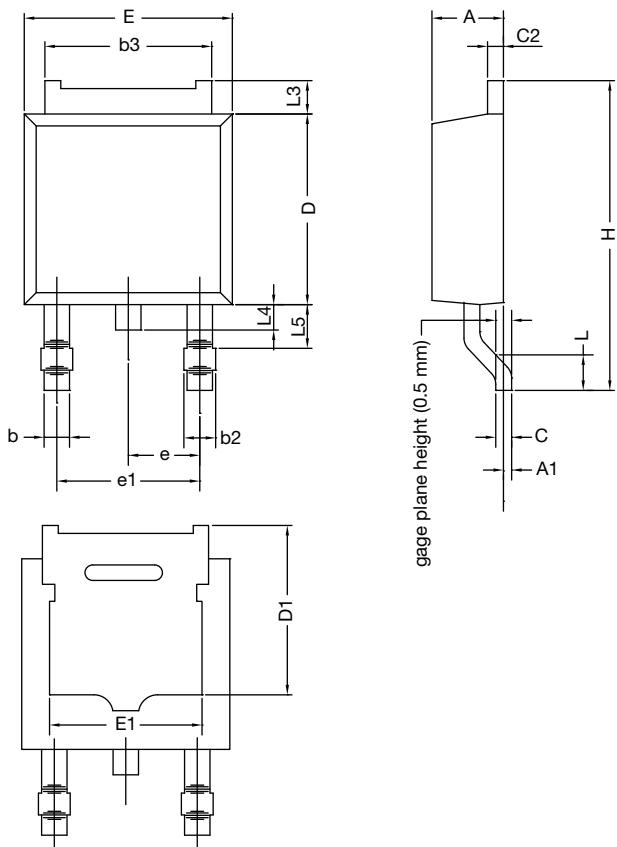


\* The power dissipation  $P_D$  is based on  $T_{J(max)} = 150$  °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



## TO-252AA CASE OUTLINE



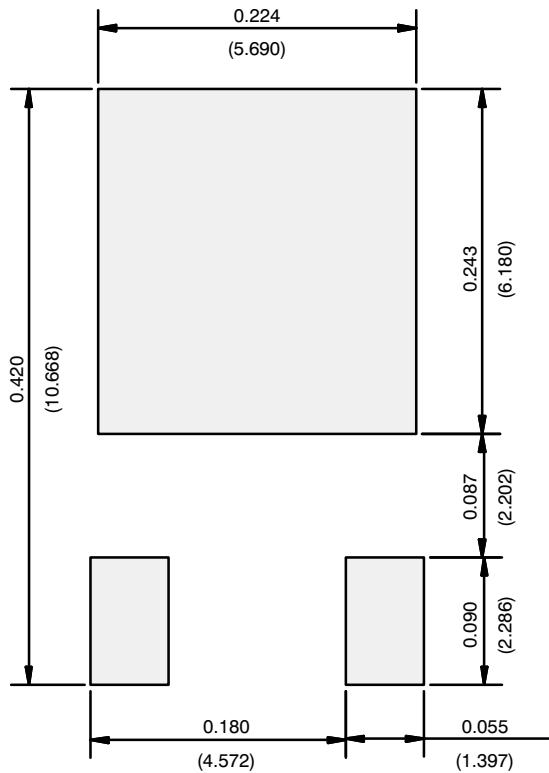
DIM.	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	2.18	2.38	0.086	0.094
A1	-	0.127	-	0.005
b	0.64	0.88	0.025	0.035
b2	0.76	1.14	0.030	0.045
b3	4.95	5.46	0.195	0.215
C	0.46	0.61	0.018	0.024
C2	0.46	0.89	0.018	0.035
D	5.97	6.22	0.235	0.245
D1	5.21	-	0.205	-
E	6.35	6.73	0.250	0.265
E1	4.32	-	0.170	-
H	9.40	10.41	0.370	0.410
e	2.28 BSC		0.090 BSC	
e1	4.56 BSC		0.180 BSC	
L	1.40	1.78	0.055	0.070
L3	0.89	1.27	0.035	0.050
L4	-	1.02	-	0.040
L5	1.14	1.52	0.045	0.060

ECN: X12-0247-Rev. M, 24-Dec-12  
DWG: 5347

**Note**

- Dimension L3 is for reference only.

**RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)**



Recommended Minimum Pads  
Dimensions in Inches/(mm)

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